ABSOLUTE MAXIMUM RATINGS

V _{CC} to GND0.3V to +6V	Continuous Power Dissipation ($T_A = +70^{\circ}C$)
OUT, A, B to GND0.3V to (V _{CC} + 0.3V)	5-Pin SC70 (derate 3.1mW/°C above +70°C)245mW
ESD Protection (Human Body Model)> 2000V	Operating Temperature Range55°C to +125°C
Current into Any Pin10mA	Junction Temperature+150°C
Output Short-Circuit DurationContinuous	Storage Temperature Range65°C to +150°C
	Lead Temperature (soldering, 10s)+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 $(V_{CC} = +2.7 \text{V to } +5.5 \text{V}, C_L = 1 \text{nF}, T_A = -55 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}, \text{ unless otherwise noted.})$ (Note 1)

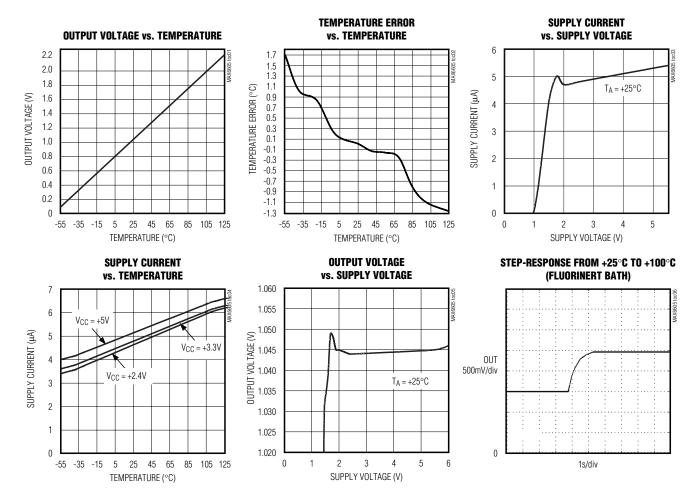
PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
			T _A = +25°C		±0.75		
Temperature Error $V_{OUT} = 0.744 + (0.0119 \times T^{\circ}C) + (1.604 \times 10^{-6} \times T^{2})V$ (Note 2)		V _{CC} = +3.3V	$T_A = -0^{\circ}C \text{ to } +70^{\circ}C$	-3.0		+3.0	°C
			$T_A = -20^{\circ}C \text{ to } +85^{\circ}C$	-3.8		+3.8	
			$T_A = -40^{\circ}C \text{ to } +100^{\circ}C$	-5.0		+5.0	
			$T_A = -55^{\circ}C \text{ to } +125^{\circ}C$	-5.8		+5.8	
Supply Voltage	Vcc —	$T_A = -55^{\circ}C \text{ to } +125^{\circ}C$		2.7		5.5	V
		$T_A = -40^{\circ}C \text{ to } +105^{\circ}C$		2.4		5.5	٧
Supply Current	IQ	No load			4.5	10	μΑ
Output Voltage	Vout	$T_A = 0$ °C			744		mV
Nonlinearity		$T_A = -20^{\circ}C \text{ to } +85^{\circ}C$			0.4		°C
Sensor Gain (Average Slope)		$T_A = -40^{\circ}C \text{ to } +100^{\circ}C$		11.1	11.9	12.7	mV/°C
Capacitive Load		Required for stability		1			nF
Land Danielation		$T_A = -20$ °C to +125°C, $I_{OUT} = -20\mu A$ to +20 μA				20	m°C/u^
Load Regulation		$T_A = -55^{\circ}C$, $I_{OUT} = -10$	μΑ to +10μΑ			20	m°C/μA

Note 1: All parameters are measured at $T_A = +25$ °C. Specifications over temperature range are guaranteed by design.

Note 2: Error (expressed in °C) is defined as the difference between the calculated and measured values of output voltage. Guaranteed by design to 5 sigma.

Typical Operating Characteristics

 $(V_{CC} = +3.3V, C_S = 0.1\mu F, C_L = 1nF, unless otherwise noted.)$



Pin Description

PIN	NAME	FUNCTION
1	Vcc	Supply Input. Decouple with a 0.1μF capacitor to GND.
2	А	Must be connected to GND.
3	OUT	Temperature Sensor Output, C _L ≥ 1nF
4	В	Must be connected to V _{CC} .
5	GND	Ground

Detailed Description

The MAX6605 analog output temperature sensor's output voltage is a linear function of its die temperature. The slope of the output voltage is 11.9mV/°C, and there is a 744mV offset at 0°C to allow measurement of negative temperatures. The MAX6605 has three terminals: VCC, GND, and OUT. The maximum supply current is 10 μ A, and the supply voltage range is from +2.4V to +5.5V for the -40°C to +105°C temperature range and +2.7V to +5.5V for the -55°C to +125°C temperature range. The temperature error is <1°C at TA = +25°C, <3.8°C from TA = -20°C to +85°C, and <5.8°C from TA = -55°C to +125°C.

Nonlinearity

The benefit of silicon analog temperature sensors over thermistors is linearity over extended temperatures. The nonlinearity of the MAX6605 is typically 0.4°C over the -20°C to +85°C temperature range.

Transfer Function

The temperature-to-voltage transfer function has an approximately linear positive slope and can be described by the equation:

$$V_{OUT} = 744 \text{mV} + (T \times 11.9 \text{mV/}^{\circ}\text{C})$$

where T is the MAX6605's die temperature in °C.

Therefore:

$$T(^{\circ}C) = (V_{OUT} - 744 \text{mV}) / 11.9 \text{mV}/^{\circ}C$$

To account for the small amount of curvature in the transfer function, use the equation below to obtain a more accurate temperature reading:

$$V_{OUT} = 0.744V + 0.0119V/^{\circ}C \times T(^{\circ}C) + 1.604 \times 10^{-6} V/^{\circ}C^{2} \times (T(^{\circ}C))^{2}$$

Applications Information

Sensing Circuit Board and Ambient Temperatures

Temperature sensor ICs like the MAX6605 that sense their own die temperatures must be mounted on, or close to, the object whose temperature they are intended to measure. Because there is a good thermal path between the SC70 package's metal leads and the IC die, the MAX6605 can accurately measure the temperature of the circuit board to which it is soldered. If the sensor is intended to measure the temperature of a heatgenerating component on the circuit board, it should be mounted as close as possible to that component and should share supply and ground traces (if they are not noisy) with that component where possible. This will maximize the heat transfer from the component to the sensor.

The thermal path between the plastic package and the die is not as good as the path through the leads, so the MAX6605, like all temperature sensors in plastic packages, is less sensitive to the temperature of the surrounding air than it is to the temperature of its leads. It can be successfully used to sense ambient temperature if the circuit board is designed to track the ambient temperature.

As with any IC, the wiring and circuits must be kept insulated and dry to avoid leakage and corrosion, especially if the part will be operated at cold temperatures where condensation can occur.

The thermal resistance junction to ambient (θ_{JA}) is the parameter used to calculate the rise of a device junction temperature (T_J) due to its power dissipation. For the MAX6605, use the following equation to calculate the rise in die temperature:

$$T_J = T_A + \theta_{JA} ((V_{CC} \times I_Q) + (V_{CC} - V_{OUT}) I_{OUT})$$

The MAX6605 is a very-low-power temperature sensor and is intended to drive very light loads. As a result, the temperature rise due to power dissipation on the die is insignificant under normal conditions. For example, assume that the MAX6605 is operating from a +3V supply at +21.6°C (VOUT = 1V) and is driving a 100k Ω load (IOUT = 10 μ A). In the 5-pin SC70 package, the die temperature will increase above the ambient by:

$$T_J - T_A = \theta_{JA} ((V_{CC} \times I_Q) + (V_{CC} - V_{OUT}) I_{OUT}) = 324^{\circ}C/W \times ((3V \times 10\mu A) + (3V - 1V) \times 10\mu A) = 0.0162^{\circ}C$$

Therefore, the error caused by power dissipation will be negligible.

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Capacitive Loads

The MAX6605 can drive unlimited load capacitance. For stable operation load capacitance should be ≥ 1 nF.

_Chip Information

TRANSISTOR COUNT: 573

Package Information

For the latest package outline information and land patterns, go to **www.maxim-ic.com/packages**. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	DOCUMENT NO.
5 SC70	X5-1	<u>21-0076</u>

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	10/00	Initial release	_
1	8/04	_	_
2	11/08	Corrected the parameter unit for VOUT in the Transfer Function section.	4
3	12/09	Added lead-free and automotive-qualified parts to the Ordering Information table.	1

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MAX6605MXK+T MAX6605MXK-T